

63

## PJQ5858A-AU

## 60V Dual N-Channel Enhancement Mode MOSFET

16 A

Voltage

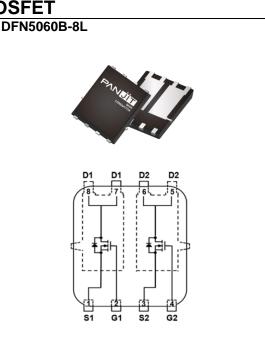
60 V Current

### Features

- $R_{DS(ON)}$ ,  $V_{GS}@10V$ ,  $I_D@8A < 50m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_D@4A < 60m\Omega$
- Excellent FOM
- Logic Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### **Mechanical Data**

- Case : DFN5060B-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.092 grams



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETE	SYMBOL	LIMIT		
Drain-Source Voltage		V <sub>DS</sub>	60	V
Gate-Source Voltage		V <sub>GS</sub>	±20	
Continuous Drain Current <sup>(Note 3)</sup>	T <sub>C</sub> =25°C		16	
	Tc=100°C	I <sub>D</sub>	12	A
Pulsed Drain Current <sup>(Note 1)</sup>	T <sub>C</sub> =25°C	I <sub>DM</sub>	64	
Power Dissipation	T <sub>C</sub> =25°C	5	25	14/
	Tc=100°C	PD	12.5	
Continuous Drain Current <sup>(Note 4)</sup>	T <sub>A</sub> =25°C		5	
	T <sub>A</sub> =70°C	ID	4.5	— A
Power Dissipation	T <sub>A</sub> =25°C	D	2.5	
	T <sub>A</sub> =70°C	PD	1.8	W
Single Pulse Avalanche Energy <sup>(Note 5)</sup>		Eas	1.6	mJ
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~175	°C
Thermal Resistance <sup>(Note 4)</sup>	Junction to Case	R <sub>θJC</sub>	6	°C/W
	Junction to Ambient	R <sub>θJA</sub>	60	C/W



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### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static		•				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	60	-	-	- V 2.5
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	1	1.7	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =8A	-	34	50	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A	-	38	60	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =60V, $V_{GS}$ =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
Dynamic <sup>(Note 6)</sup>						
Total Gate Charge	Qg	V <sub>DS</sub> =48V, I <sub>D</sub> =8A, V <sub>GS</sub> =10V	-	13	-	nC
Gate-Source Charge	Qgs		-	2.1	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	2.9	-	
Input Capacitance	Ciss	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V, f=1MHz	-	609	-	pF
Output Capacitance	Coss		-	43	-	
Reverse Transfer Capacitance	Crss		-	14	-	
Gate resistance	Rg	f=1MHz	-	3.7	-	Ω
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DS</sub> =48V, I <sub>D</sub> =8A, V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω (Note 2,3)	-	8.4	-	ns
Turn-On Rise Time	tr		-	33	-	
Turn-Off Delay Time	td(off)		-	32	-	
Turn-Off Fall Time	tf		-	27	-	
Drain-Source Diode						
Diode Forward Current	Is	T 05º0	-	-	16	A
Pulsed Diode Forward Current	I <sub>SM</sub>	T <sub>c</sub> =25°C	-	-	64	
Diode Forward Voltage	V <sub>SD</sub>	Is=1A, V <sub>GS</sub> =0V	-	0.72	1	V
Reverse Recovery Time	Trr	V <sub>GS</sub> =0V, I <sub>S</sub> =8A	-	25	-	ns
Reverse Recovery Charge	Qrr	dls/dt=100A/us	-	12	-	nC

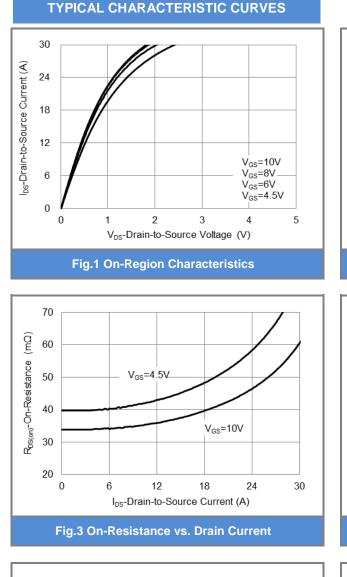
NOTES :

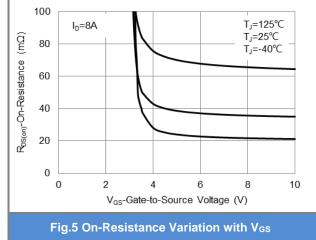
- 1. Pulse width100us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an  $R_{\theta JC}$ = 6°C/W.
- 4.  $R_{\theta,JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 5. The test condition is L=0.1mH, I\_{AS}=5.6A, V\_{DD}=30V, V\_{GS}=10V, Starting T\_J=25^{\circ}C.
- 6. Guaranteed by design, not subject to production testing.

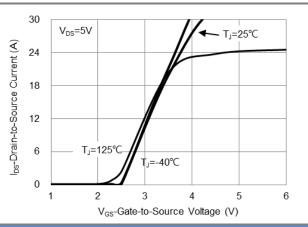
SEMI CONDUCTOR

ΡΛΝ

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**Fig.2 Transfer Characteristics** 

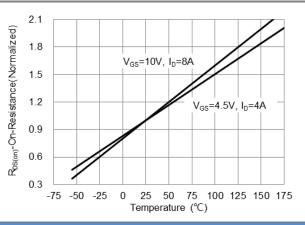
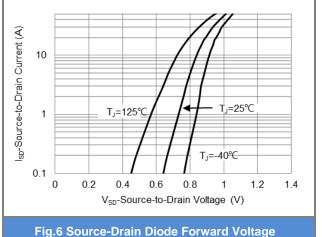


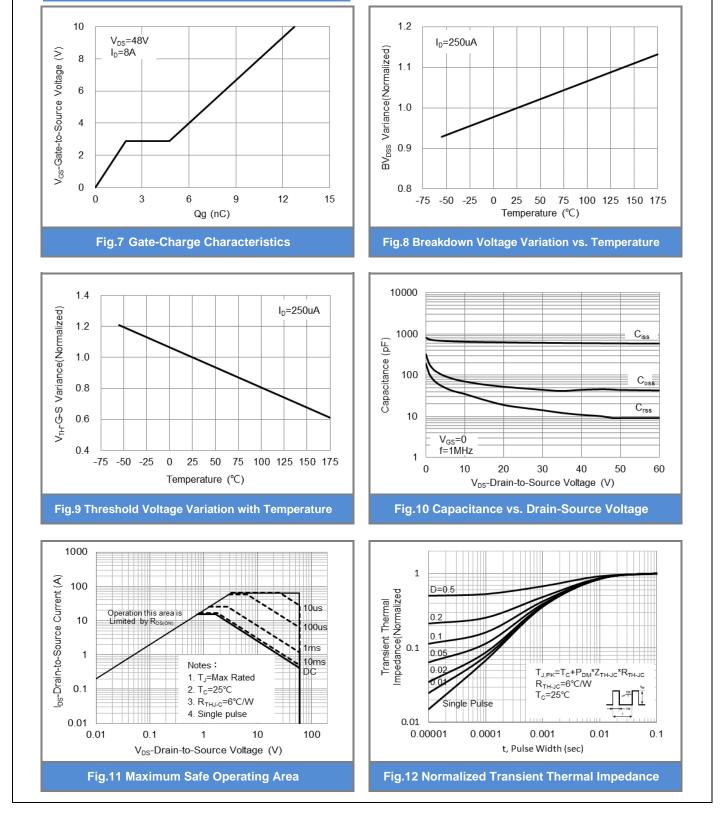
Fig.4 On-Resistance vs. Junction temperature



March 3,2023

#### PJQ5858A-AU-REV.00





## TYPICAL CHARACTERISTIC CURVES



**PJQ5858A-AU** 



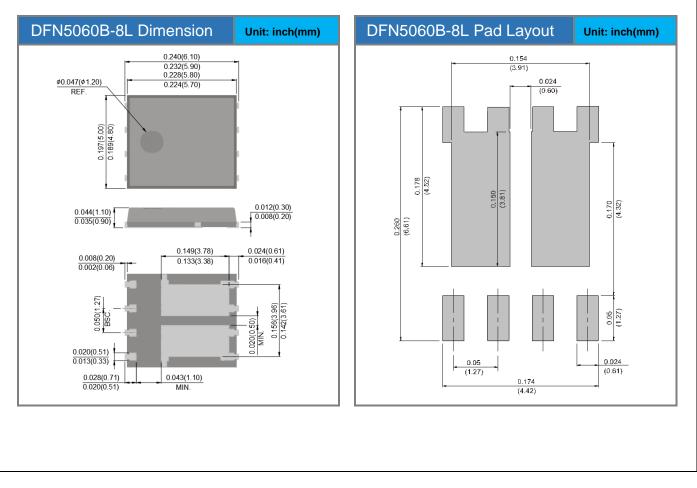


# PJQ5858A-AU

### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ5858A-AU_R2_000A1	DFN5060B-8L	3K pcs / 13" reel	Q5858A	Halogen free RoHS compliant

### Packaging Information & Mounting Pad Layout





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